# Infrared Light Emitting Diode OP205CL



#### Features:

- High power GaAlAs
- Narrow beam angle—near parallel beam
- 875 nm wavelength
- TO-46 package
- · Wide operating temperature range



### **Description:**

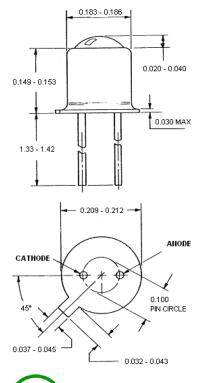
The **OP205CL** is a high efficiency GaAlAs infrared LED mounted in a TO-46 metal can package. The device features a special dome lens that allows a very narrow beam angle. The result is a near parallel beam that is useful in applications that requires a collimated light source with a uniform intensity pattern.

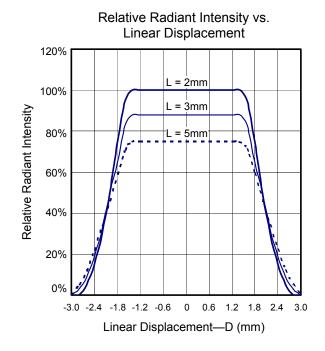
OP205CL LED is mechanically and spectrally matched to OP800 series phototransistors.

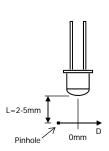
### **Applications:**

- · Optical encoders
- · Triangulation sensors
- · Long distance sensing

| Ordering Information |                |                        |                     |                |  |  |  |  |
|----------------------|----------------|------------------------|---------------------|----------------|--|--|--|--|
|                      | Part<br>Number | LED Peak<br>Wavelength | Total Beam<br>Angle | Lead<br>Length |  |  |  |  |
|                      | OP205CL        | 875 nm                 | 10°                 | 34mm           |  |  |  |  |









**RoHS** 

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

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### Absolute Maximum Ratings T<sub>A</sub> = 25° C unless otherwise noted

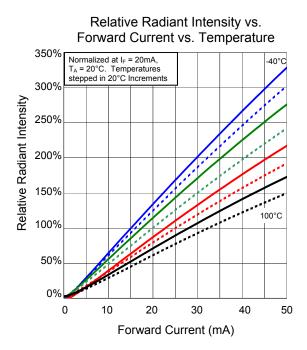
| Storage Temperature Range   | -40° C to +125° C     |
|-----------------------------|-----------------------|
| Operating Temperature Range | -40° C to +100° C     |
| Lead Soldering Temperature  | 260° C <sup>(1)</sup> |
| Reverse Voltage             | 3.0 V                 |
| Continuous Forward Current  | 50 mA                 |
| Power Dissipation           | 160 mW <sup>(2)</sup> |

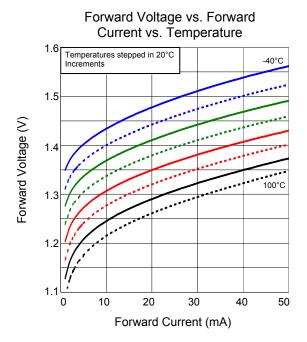
### Electrical Characteristics (T<sub>A</sub> = 25°C unless otherwise noted)

| SYMBOL         | PARAMETER                                 | MIN | TYP  | MAX | UNITS | CONDITIONS                           |
|----------------|---|-----|------|-----|-------|--------------------------------------|
| Po             | Radiant Intensity                         | 8.5 | 12.0 | 1   | mW    | I <sub>F</sub> = 50mA <sup>(3)</sup> |
| V <sub>F</sub> | Forward Voltage                           | -   | -    | 2.0 | V     | I <sub>F</sub> = 50mA                |
| I <sub>R</sub> | Reverse Current                           | -   | ı    | 10  | μΑ    | V <sub>R</sub> = 3.0V                |
| $\lambda_{P}$  | Peak Emission Wavelength                  | -   | 875  | -   | nm    | I <sub>F</sub> = 20mA                |
| $\Theta_{HP}$  | Total Emission Angle at Half Power Points | -   | 6    | 10  | Deg.  | I <sub>F</sub> = 20mA                |

#### Notes:

- Solder time less than 5 seconds at temperature extreme.
- 2. De-rate linearly at 2.17 mW/° C above 25° C.
- 3. Total Optical Power (Po) is measured by OPTEK Technology equipment.





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